

1200V, 75A, Trench FS II Fast IGBT

General Description:

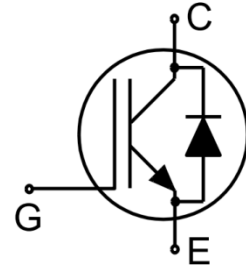
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low $V_{CE(sat)}$
- High speed switching
- Positive temperature coefficient in $V_{CE(sat)}$
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

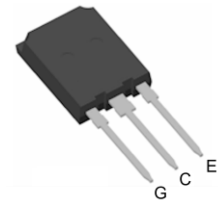
- PV power
- Three-level Solar String Inverter
- UPS



Schematic diagram

Package Marking and Ordering Information

Device	Device Package	Device Marking
NCE75TS120VTP	TO-247P	NCE75TS120VTP



TO-247P

Absolute Maximum Ratings ($T_C=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate- Emitter Voltage	± 30	V
I_C	Collector Current	150	A
	Collector Current @ $T_C = 100^\circ\text{C}$	75	A
I_{Cpuls}	Pulsed Collector Current, t_p limited by T_{jmax}	300	A
-	Turn off safe operating area, $V_{CE}=1200\text{V}$, $T_J=175^\circ\text{C}$	300	A
I_F	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	75	A
I_{FM}	Diode Maximum Forward Current	300	A
P_D	Power Dissipation @ $T_C = 25^\circ\text{C}$	833	W
	Power Dissipation @ $T_C = 100^\circ\text{C}$	417	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to +175	$^\circ\text{C}$
T_L	Maximum Temperature for Soldering	260	$^\circ\text{C}$

Thermal Characteristic

Symbol	Parameter	Value	Units
R _{θJC}	Thermal Resistance, Junction to case for IGBT	0.18	°C/W
R _{θJC}	Thermal Resistance, Junction to case for Diode	0.40	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	40	°C/W

Electrical Characteristics (T_c=25°C unless otherwise noted)

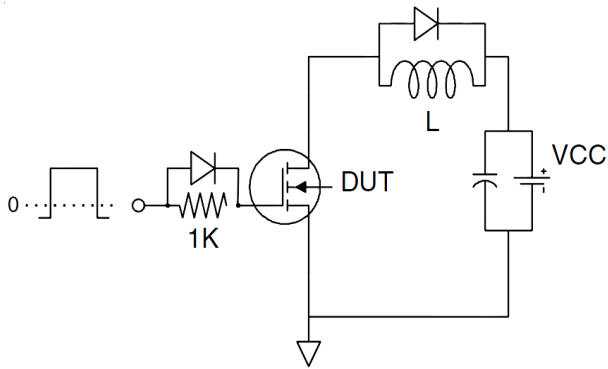
Symbol	Parameter	Conditions	Value			Units	
			Min.	Typ.	Max.		
Static Characteristics							
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V, I _{CE} =3mA	1200	--	--	V	
I _{CES}	Collector-Emitter Leakage Current	V _{GE} =0V, V _{CE} =1200V	--	--	400	μA	
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30V, V _{CE} =0V	--	--	200	nA	
I _{GES(R)}	Gate to Emitter Reverse Leakage	V _{GE} =-30V, V _{CE} =0V	--	--	200	nA	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C =75A, T _J =25°C	--	1.70	1.95	V	
		V _{GE} =15V, T _J =175°C	--	1.95	--	V	
V _{GE(th)}	Gate Threshold Voltage	I _C =3mA, V _{CE} =V _{GE}	4.5	--	6.0	V	
Dynamic Characteristics							
C _{ies}	Input Capacitance	V _{CE} =30V, V _{GE} =0V, f=1MHz	--	9747	--	pF	
C _{oes}	Output Capacitance		--	327	--		
C _{res}	Reverse Transfer Capacitance		--	271	--		
Q _g	Total Gate Charge	V _{CC} =960V, I _C =75A, V _{GE} =15V	--	572	--	nC	
Q _{ge}	Gate to Emitter Charge		--	69	--		
Q _{gc}	Gate to Collector Charge		--	368	--		
Switching Characteristics							
t _{d(ON)}	Turn-on Delay Time	V _{CE} =600V, I _C =75A, V _{GE} =0/15V, R _g =8Ω Inductive Load	--	19	--	ns	
t _r	Rise Time		--	17	--		
t _{d(OFF)}	Turn-Off Delay Time		--	170	--		
t _f	Fall Time		--	18	--		
E _{on}	Turn-On Switching Loss		V _{CE} =600V, I _C =75A, V _{GE} =0/15V, R _g =8Ω	--	5.6	--	mJ
E _{off}	Turn-Off Switching Loss			--	2.7	--	
E _{ts}	Total Switching Loss			--	8.3	--	
E _{on}	Turn-On Switching Loss		V _{CE} =600V, I _C =75A, V _{GE} =0/15V, R _g =8Ω T _J =175°C	--	7.1	--	mJ
E _{off}	Turn-Off Switching Loss			--	3.6	--	
E _{ts}	Total Switching Loss	--		10.7	--		

Electrical Characteristics of the Diode (T_c= 25°C unless otherwise specified)

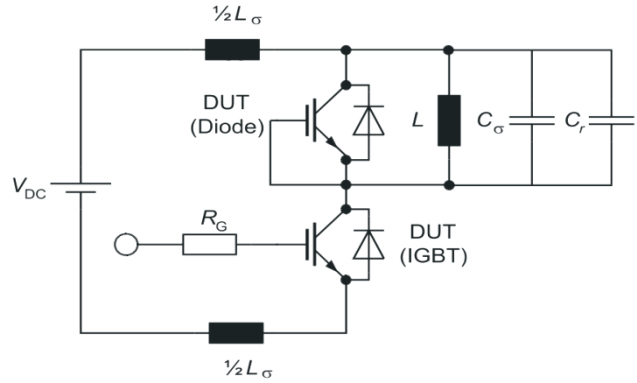
Symbol	Parameter	Conditions	Rating			Units
			Min.	Typ.	Max.	
V _{FM}	Diode Forward Voltage	I _F =75A	--	2.0	2.6	V
T _{rr}	Reverse Recovery Time	I _F =37.5A, di/dt=800A/us	--	126	--	ns
I _{RRM}	Diode Peak Reverse Recovery Current		--	28	--	A
Q _{rr}	Reverse Recovery Charge		--	3.7	--	μC

Test Circuit

1) Gate Charge Test Circuit

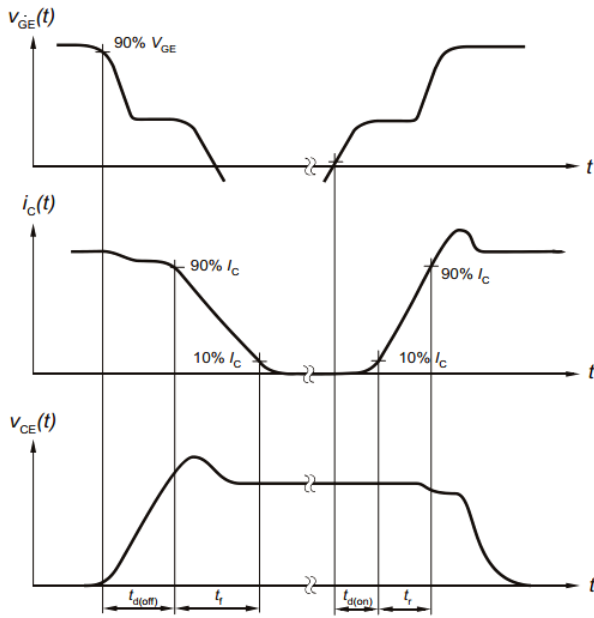


2) Switch Time Test Circuit

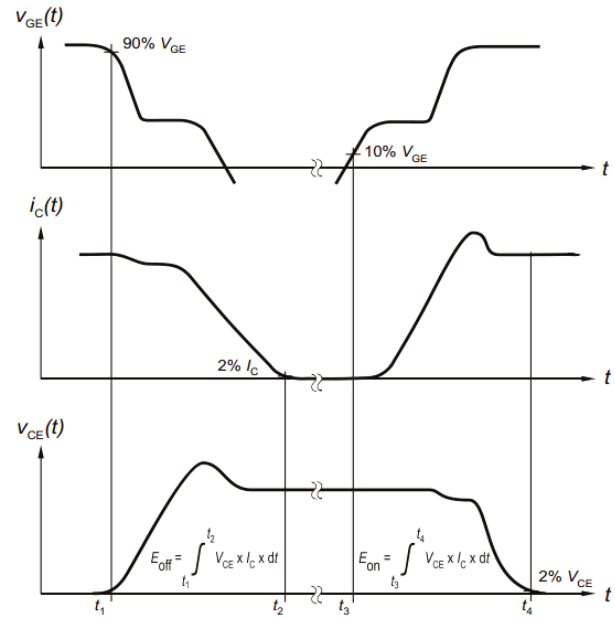


Switching characteristics

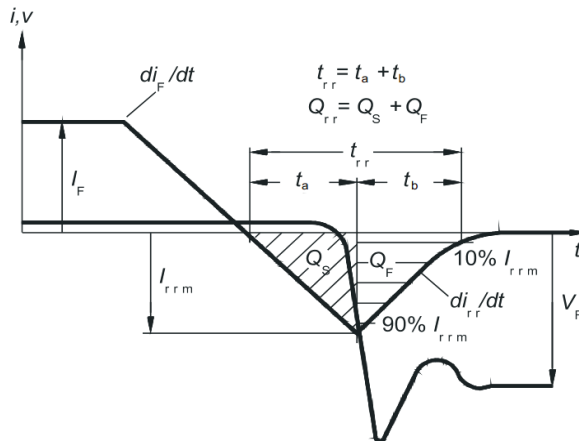
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics



Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

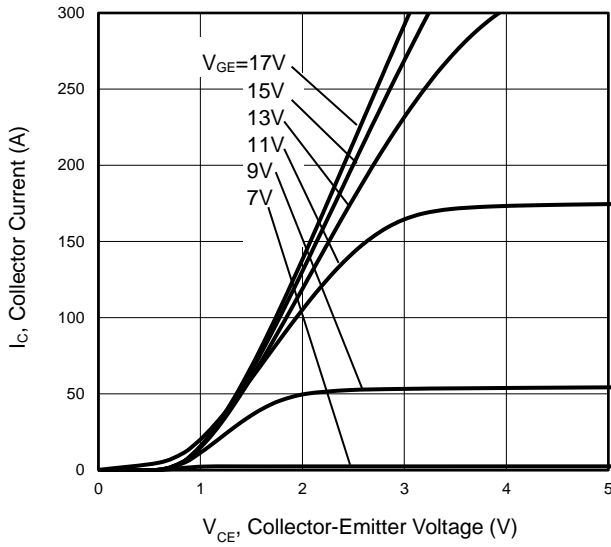


Figure 2 Transfer Characteristics

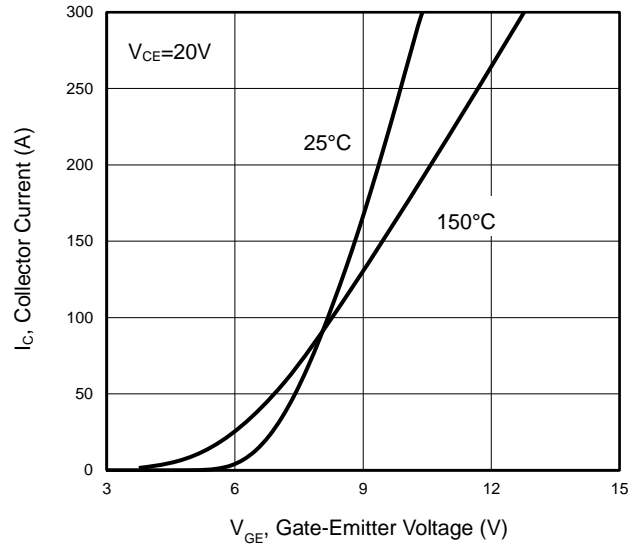


Figure 3 $V_{CE(sat)}$ vs. Case Temperature

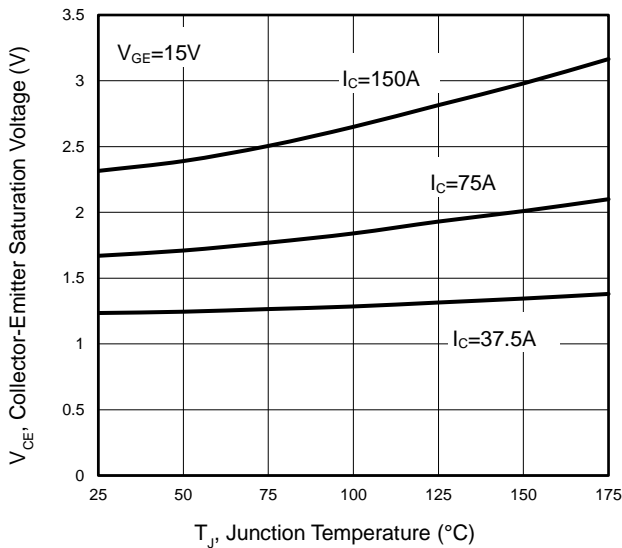


Figure 4 Saturation Voltage vs. V_{GE}

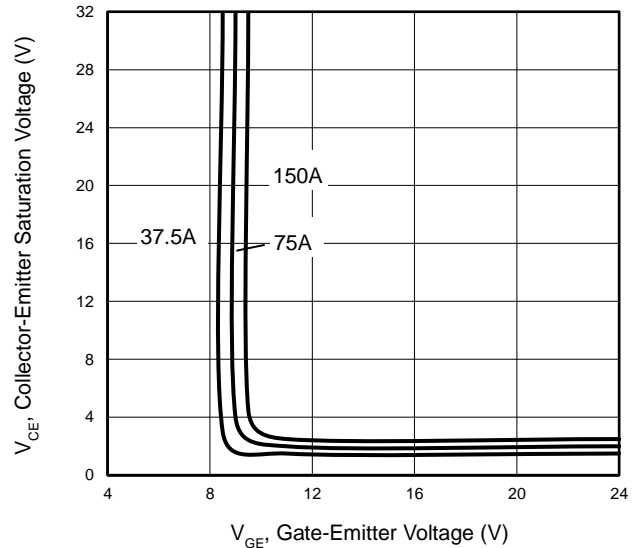


Figure 5 Capacitance Characteristics

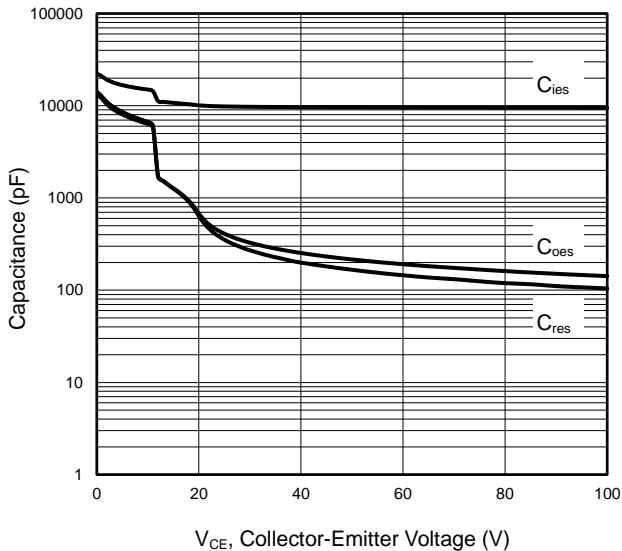
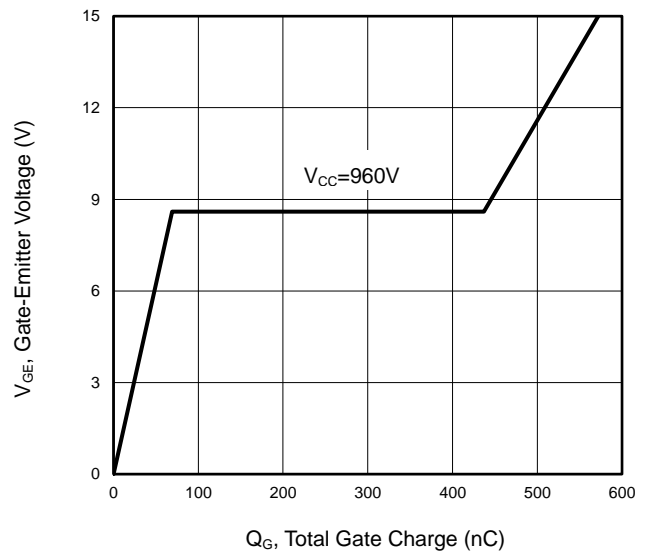


Figure 6 Gate Charge Wave Form



Typical Electrical and Thermal Characteristics

Figure 7 Forward Characteristics

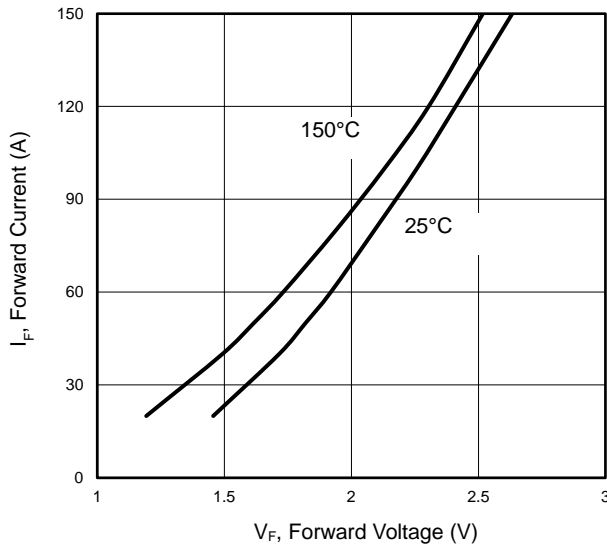


Figure 8 V_F vs. Temperature

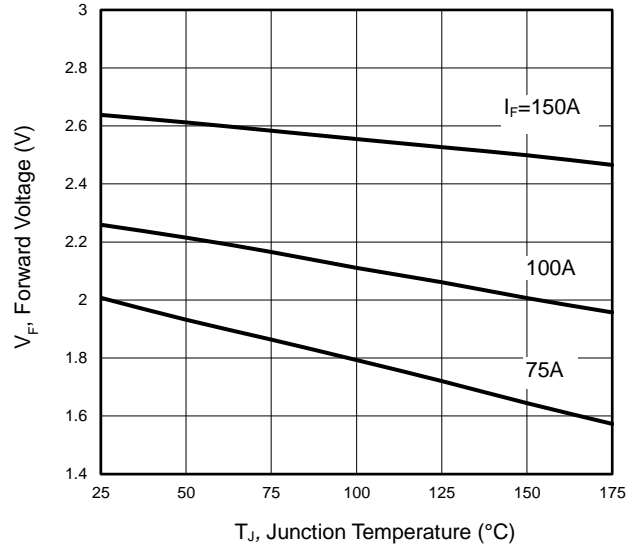


Figure 9 Switching Energy vs. Temperature

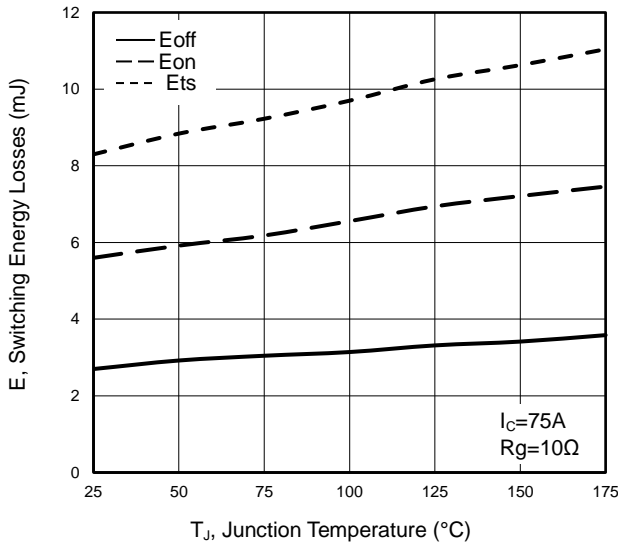


Figure 10 Forward Bias Safe Operating Area

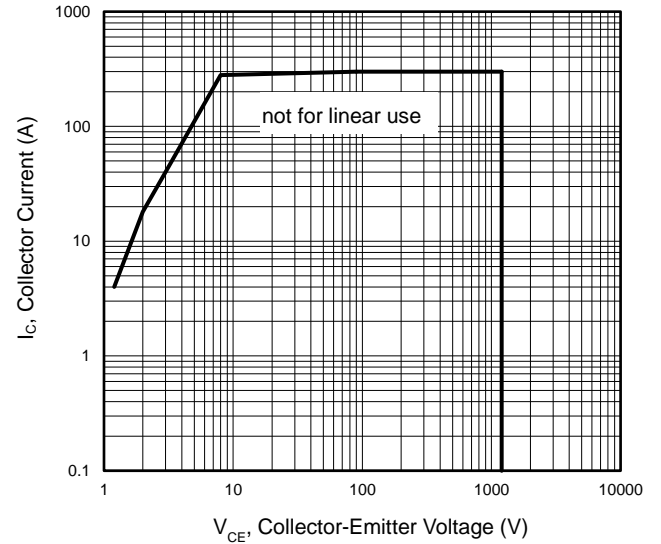


Figure 11 Gate-Emmitter Threshold Voltage as a Function of Junction Temperature

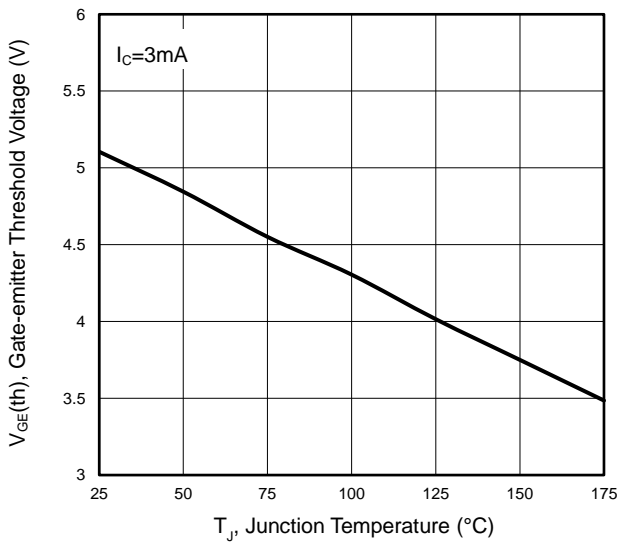
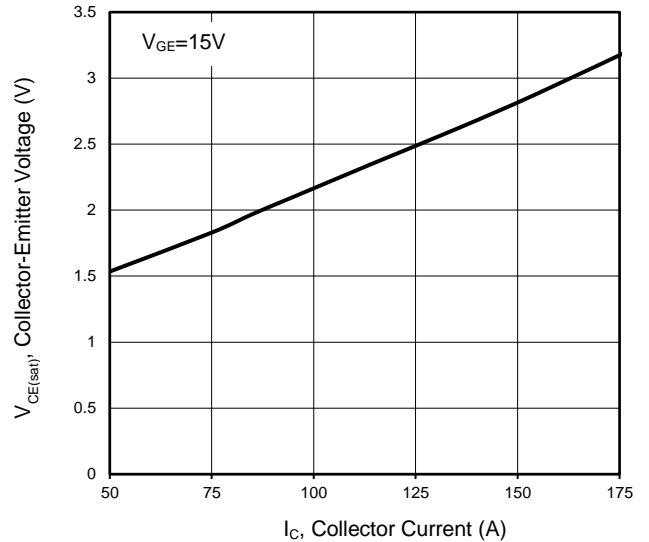


Figure 12 Typical Collector-Emmitter Saturation Voltage as a function of Collector Current



Typical Electrical and Thermal Characteristics

Figure 13 Switching Loss vs. R_G

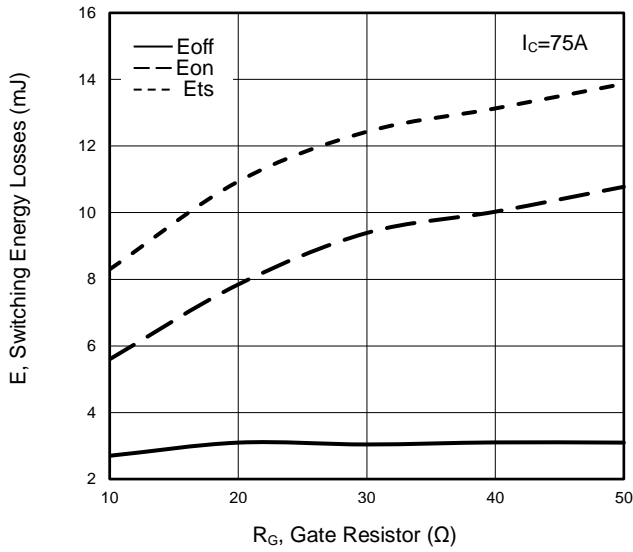


Figure 14 Switching Loss vs. Collector Current

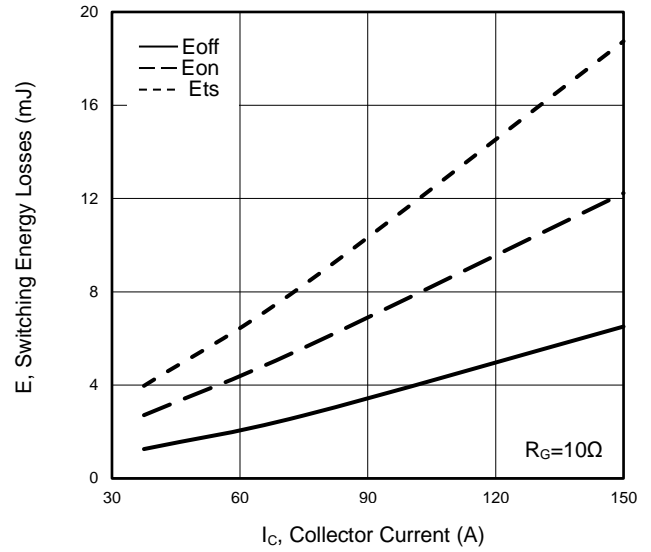


Figure 15 Switching Loss vs. Collector Current

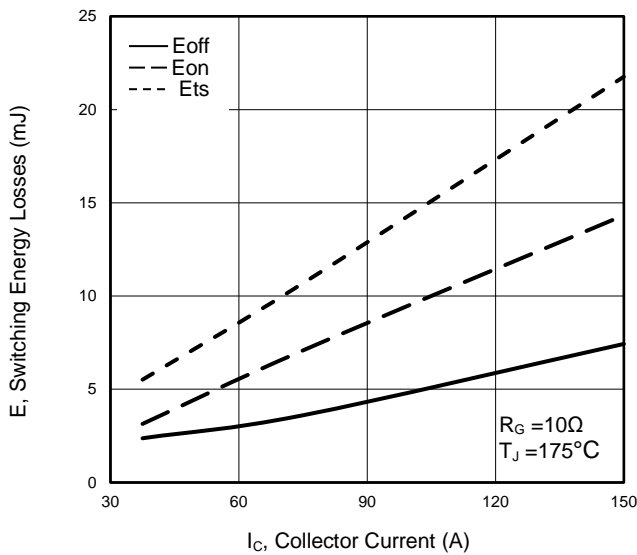


Figure 16 P_{tot} vs. Case Temperature

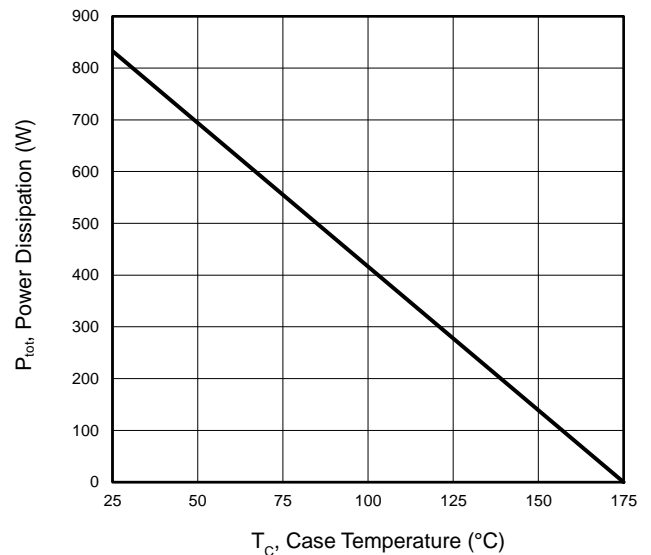


Figure 17 V_{CES} vs. Case Temperature

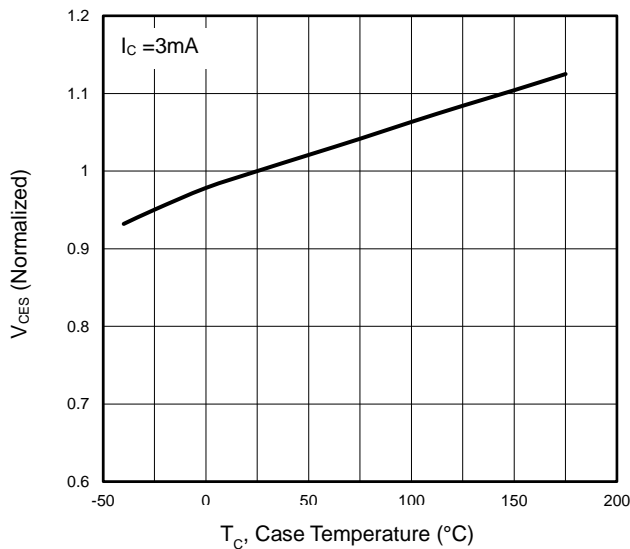
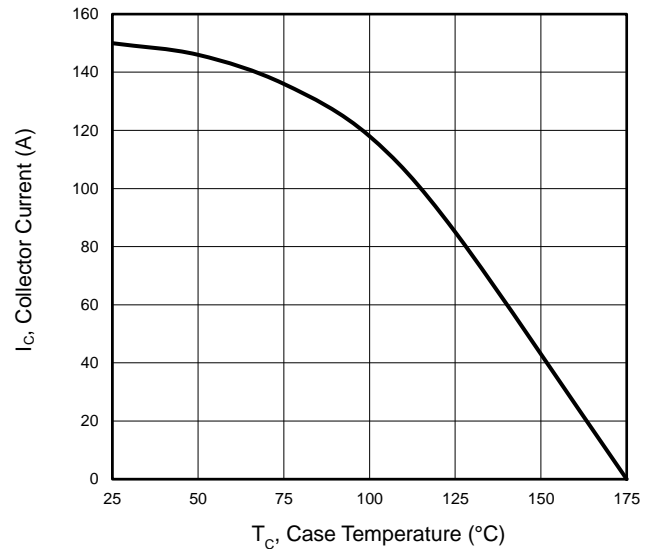


Figure 18 I_C vs. Temperature



Typical Electrical and Thermal Characteristics

Figure 19 Switching Time vs. I_C

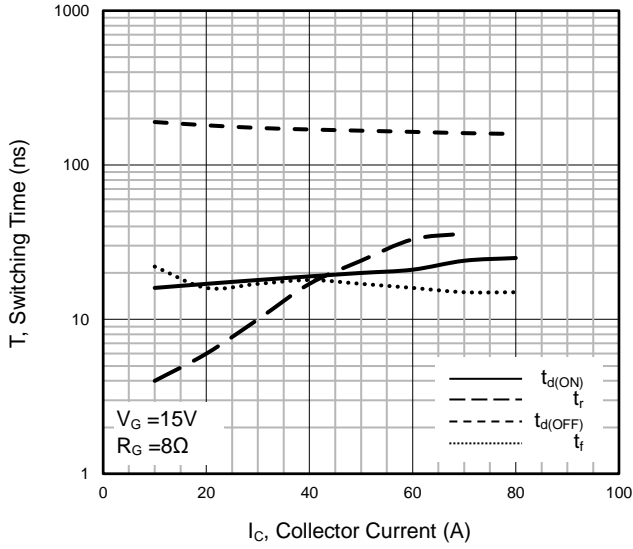


Figure 20 Switching Time vs. R_G

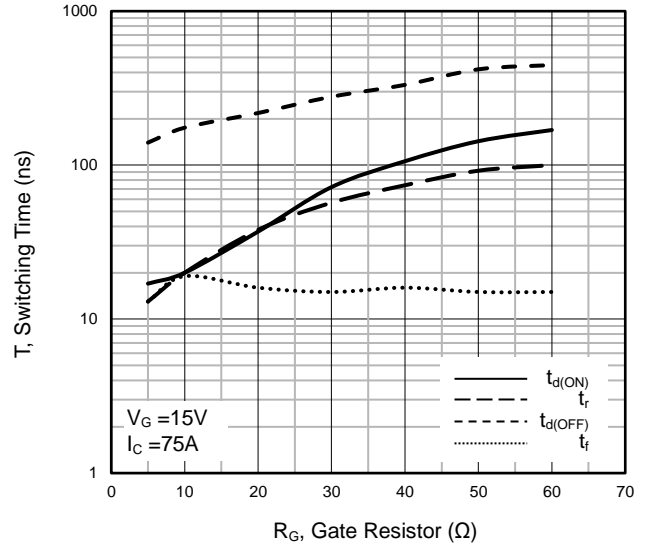


Figure 21 Switching Time vs. I_C

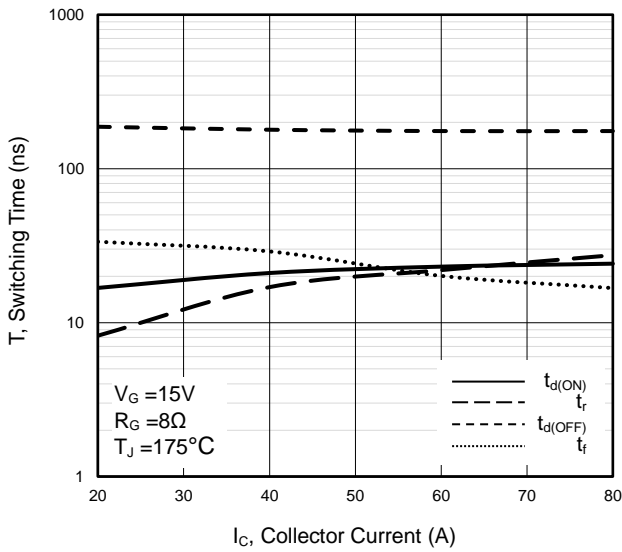
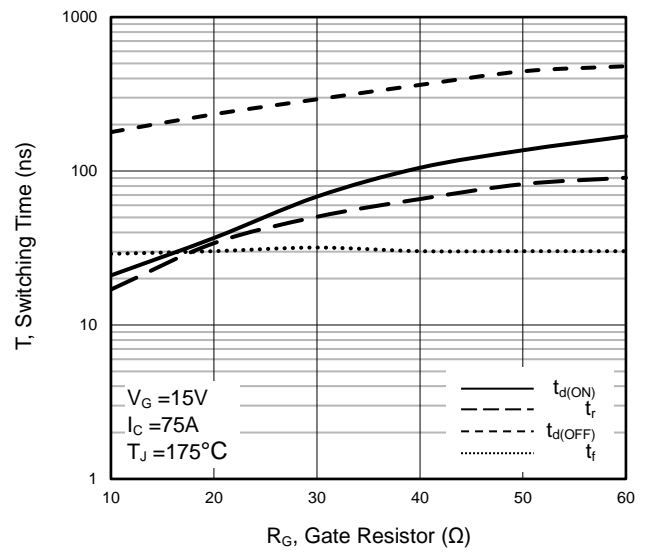
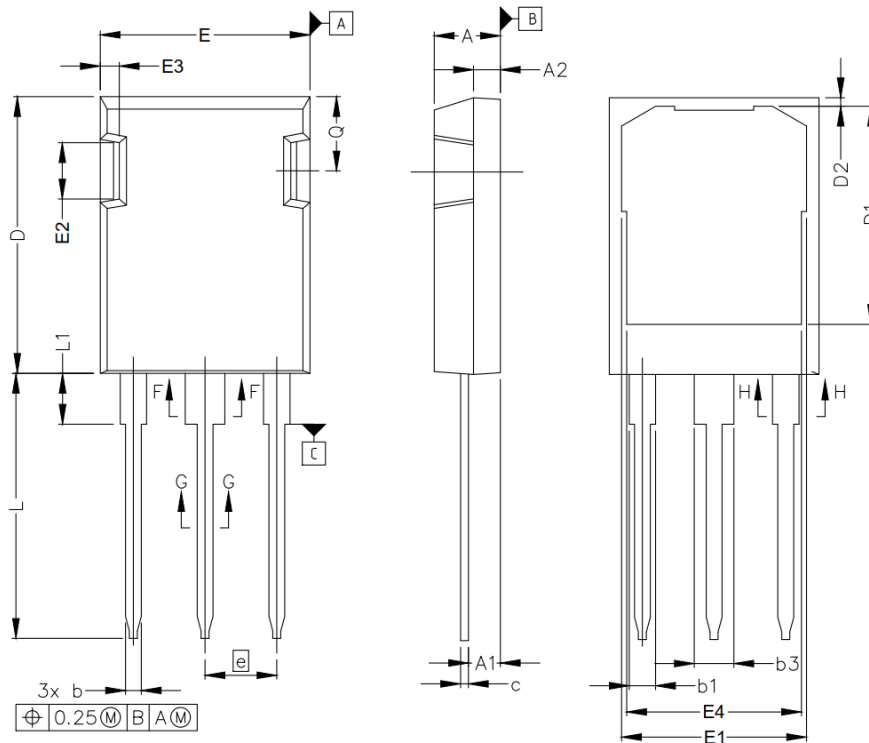


Figure 22 Switching Time vs. R_G

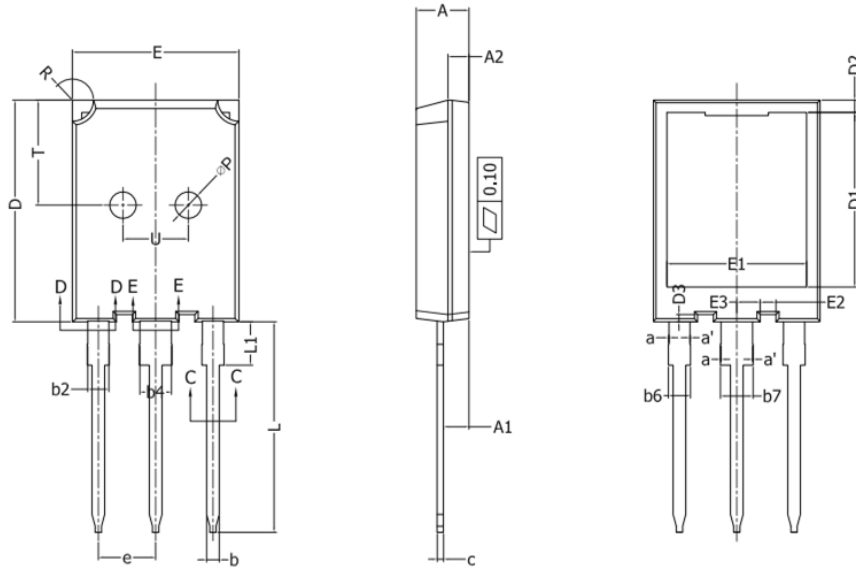


TO-247P-B Package Information



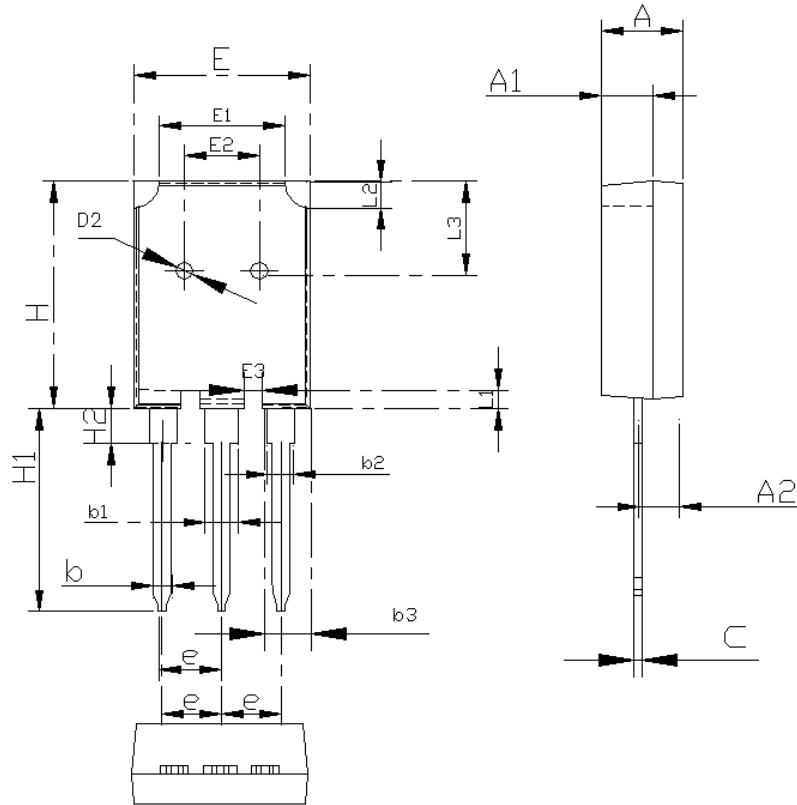
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.83	5.21	0.19	0.21
A1	2.29	2.54	0.09	0.10
A2	1.91	2.16	0.08	0.09
b	1.07	1.33	0.04	0.05
b1	1.91	2.41	0.08	0.09
b3	2.87	3.38	0.11	0.13
c	0.55	0.68	0.02	0.03
D	20.80	21.10	0.82	0.83
D1	16.25	17.65	0.64	0.69
D2	0.50	0.80	0.02	0.03
E	15.75	16.13	0.62	0.64
E1	13.10	14.15	0.52	0.56
E2	3.68	5.10	0.14	0.20
E3	1.00	1.90	0.04	0.07
E4	12.38	13.43	0.49	0.53
e	5.44BSC		0.21	
N	3.00		0.12	
L	19.81	20.32	0.78	0.80
L1	3.70	4.00	0.15	0.16
Q	5.49	6.00	0.22	0.24

TO-247P-P Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.90	5.10	0.193	0.201
A1	2.31	2.51	0.091	0.099
A2	1.90	2.10	0.075	0.083
a、a'	0.00	0.15	0.000	0.006
b	1.16	1.26	0.046	0.050
b2	1.96	2.06	0.077	0.081
b4	2.96	3.06	0.117	0.120
b6	-	2.25	-	0.089
b7	-	3.25	-	0.128
c	0.59	0.66	0.023	0.026
D	20.90	21.10	0.823	0.831
D1	16.25	16.85	0.640	0.663
D2	1.05	1.35	0.041	0.053
D3	0.58	0.78	0.023	0.031
E	15.70	15.90	0.618	0.626
E1	13.10	13.50	0.516	0.531
E2	1.40	1.60	0.055	0.063
E3	2.12	2.32	0.083	0.091
e	5.436 BSC		0.214 BSC	
L	19.80	20.10	0.780	0.791
L1	-	4.30	-	0.169
P	2.40	2.60	0.094	0.102
R	1.90	2.10	0.075	0.083
T	9.80	10.20	0.386	0.402
U	6.00	6.40	0.236	0.252

TO-247P-d Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.80	5.20	0.189	0.205
A1	2.80	3.20	0.110	0.126
A2	1.80	2.20	0.071	0.087
b	1.00	1.40	0.039	0.055
b1	2.90	3.30	0.114	0.130
b2	1.90	2.30	0.075	0.091
b3	3.90	4.30	0.154	0.169
c	0.45	0.75	0.018	0.030
e	5.25	5.65	0.207	0.222
E	15.60	16.00	0.614	0.630
E1	10.20	11.00	0.402	0.433
E2	6.30	6.90	0.248	0.272
E3	1.60	2.00	0.063	0.079
L1	0.35	0.65	0.014	0.026
L2	1.80	2.20	0.071	0.087
L3	9.50	10.50	0.374	0.413
H	20.50	21.50	0.807	0.846
H1	19.50	20.50	0.768	0.807
H2	3.50	4.50	0.138	0.177

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